



DO-201AD SCHOTTKY BARRIER DIODE

Reverse Voltage - 20 to 200 Volts

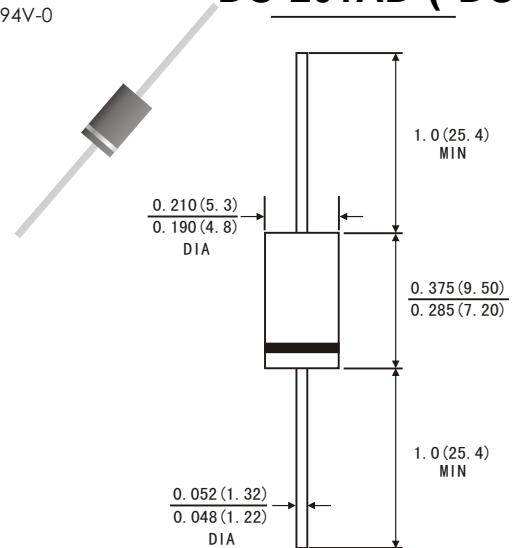
Forward Current - 3.0Ampere

SR320-SR3200

FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction ,majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss ,high efficiency
- High current capability ,Low forward voltage drop
- High surge capability
- For use in low voltage ,high frequency inverters, free wheeling ,and polarity protection applications
- High temperature soldering guaranteed:260°C/10 seconds at terminals
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

DO-201AD (DO-27)



Dimensions in inches and (millimeters)

MECHANICAL DATA

- Case: JEDEC DO-201AD molded plastic body
- Terminals: Plated axial leads, solderable per MIL-STD-750,method 2026
- Polarity: Color band denotes cathode end
- Mounting Position: Any
- Weight: 0.041 ounce, 1.15 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified ,Single phase ,half wave ,resistive or inductive load. For capacitive load,derate by 20%.)

	Symbols	SR 320	SR 330	SR 340	SR 350	SR 360	SR 380	SR 3100	SR 3150	SR 3200	Units
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	40	50	60	80	100	150	200	Volts
Maximum RMS voltage	V _{RMS}	14	21	28	35	42	56	70	105	140	Volts
Maximum DC blocking voltage	V _{DC}	20	30	40	50	60	80	100	150	200	Volts
Maximum average forward rectified current 0.375"(9.5mm) lead length (See Fig.1)	I(AV)	3.0									Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}	80.0									Amps
Maximum instantaneous forward voltage at 3.0 A(Note 1)	V _F	0.55		0.70		0.85		0.90		0.95	Volts
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1)	I _R	0.5									mA
		20			10						
Typical junction capacitance(Note 3)	C _J	250			160						pF
Typical thermal resistance (Note 2)	R _{θJA}	40.0									°C/W
	R _{θJL}	10.0									
Operating junction temperature range	T _J	-65 to+125			-65 to+150						°C
Storage temperature range	T _{STG}	-65 to+150									°C

Notes: 1.Pulse test: 300 μs pulse width,1% duty cycle

2.Thermal resistance from junction to lead vertical P.C.B. mounted , 0.5"(12.7mm)lead length with 2.5X2.5"(63.5X63.5mm)copper pads

3.Measured at 1MHz and reverse voltage of 4.0volts

RATINGS AND CHARACTERISTIC CURVES SR320 THRU SR3200

FIG.1-FORWARD CURRENT DERATING CURVE

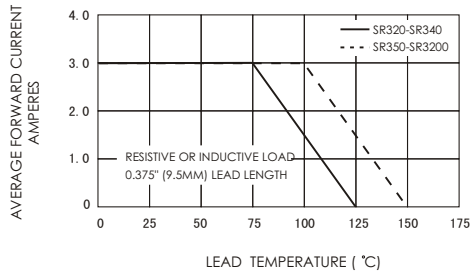


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

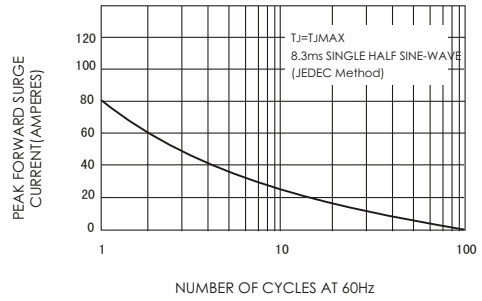


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

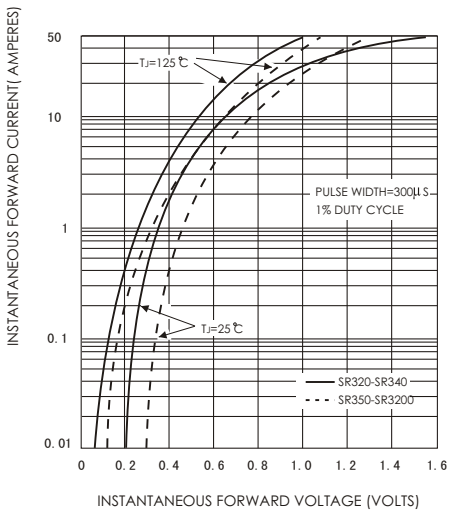


FIG.4-TYPICAL REVERSE CHARACTERISTICS

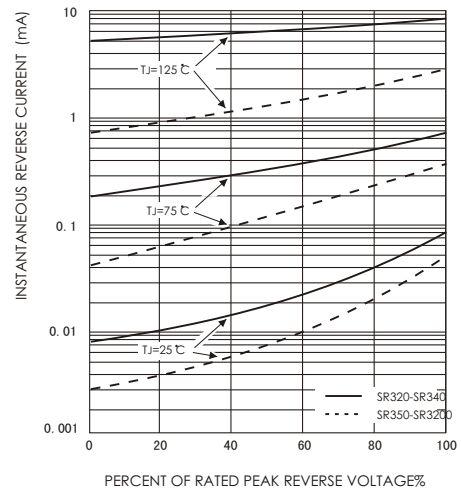


FIG.5-TYPICAL JUNCTION CAPACITANCE

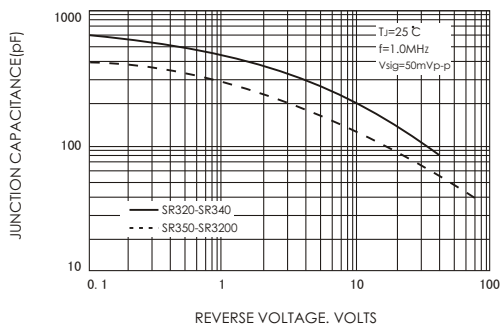
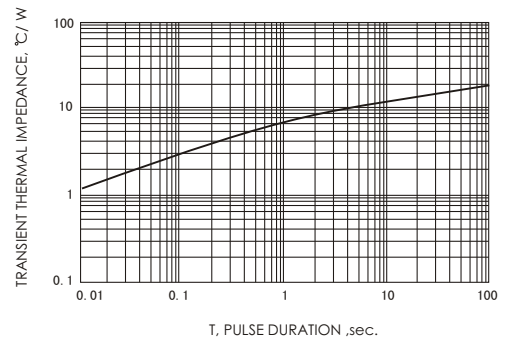


FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE



X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [Schottky Diodes & Rectifiers](#) category:

Click to view products by [HL](#) manufacturer:

Other Similar products are found below :

[MA4E2039](#) [MA4E2508M-1112](#) [MBR10100CT-BP](#) [MBR1545CT](#) [MMBD301M3T5G](#) [GS1JE-TP](#) [RB160M-50TR](#) [BAS 3010S-02LRH E6327](#)
[BAT 54-02LRH E6327](#) [NSR05F40QNXT5G](#) [NSVR05F40NXT5G](#) [NTE555](#) [JANS1N6640](#) [SB07-03C-TB-H](#) [SB1003M3-TL-W](#)
[SBAT54CWT1G](#) [SBM30-03-TR-E](#) [SK310-T](#) [SK33A-TP](#) [SK34B-TP](#) [SS3003CH-TL-E](#) [PDS3100Q-7](#) [GA01SHT18](#) [CRS10I30A\(TE85L,QM](#)
[MA4E2501L-1290](#) [MBRB30H30CT-1G](#) [BAS 70-02L E6327](#) [DMJ3940-000](#) [SB007-03C-TB-E](#) [SB10015M-TL-E](#) [SB1003M3-TL-E](#) [SK32A-](#)
[TP](#) [SK33B-TP](#) [SK35A-TP](#) [SK38B-LTP](#) [SK38B-TP](#) [NRVBM120LT1G](#) [NTE505](#) [NTSB30U100CT-1G](#) [VS-6CWQ10FNHM3](#)
[CRG04\(T5L,TEMQ\)](#) [ACDBA1100LR-HF](#) [ACDBA1200-HF](#) [ACDBA140-HF](#) [ACDBA2100-HF](#) [ACDBA240-HF](#) [ACDBA3100-HF](#)
[CDBQC0530L-HF](#) [BAT54-13-F](#) [ACDBA340-HF](#)